



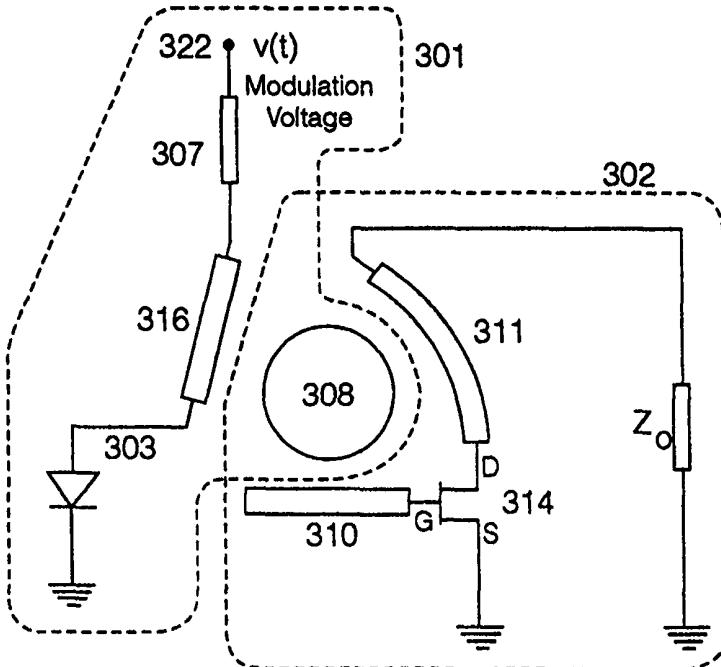
INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

(51) International Patent Classification ⁶ : H03B 5/18, G01S 7/03		A1	(11) International Publication Number: WO 99/66635
			(43) International Publication Date: 23 December 1999 (23.12.99)
(21) International Application Number: PCT/GB99/01667			
(22) International Filing Date: 9 June 1999 (09.06.99)			
(30) Priority Data: 9812936.4 16 June 1998 (16.06.98) GB 09/098,267 16 June 1998 (16.06.98) US			
(71) Applicant (for all designated States except US): MICROWAVE SOLUTIONS LIMITED [GB/GB]; Elstree Way, Borehamwood, Hertfordshire WD6 1RX (GB).			(81) Designated States: AE, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, CA, CH, CN, CU, CZ, DE, DK, EE, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MD, MG, MK, MN, MW, MX, NO, NZ, PL, PT, RO, RU, SD, SE, SG, SI, SK, SL, TJ, TM, TR, TT, UA, UG, US, UZ, VN, YU, ZA, ZW, ARIPO patent (GH, GM, KE, LS, MW, SD, SL, SZ, UG, ZW), Eurasian patent (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European patent (AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE), OAPI patent (BF, BJ, CF, CG, CI, CM, GA, GN, GW, ML, MR, NE, SN, TD, TG).
(72) Inventors; and			Published
(75) Inventors/Applicants (for US only): HALLATT, John, Gilbert [US/GB]; 30 Hempstead Lane, Potten End, Berkhamstead, Herts HP4 2SD (GB). ALDRED, Ian, Richard [GB/GB]; Penn Cottage, Whitegates Close, Croxley Green, Rickmansworth, Herts WD3 3JY (GB).			With international search report.
(74) Agents: LUNT, Mark, G., F.; Dibb Lupton Alsop, Fountain Precinct, Balm Green, Sheffield S1 1RZ (GB) et al.			

(54) Title: OSCILLATOR CIRCUIT

(57) Abstract

An oscillator circuit comprising first and second mutually electromagnetically couplable resonant circuits, the second circuit comprising a dielectric element and excitation means operable to produce a first frequency of oscillation, the first circuit comprising the dielectric element, excitation means including a two-terminal Schottky device, preferably a Schottky diode, operable, responsive to an applied signal, to vary the resonant frequency of the first resonant circuit, and thereby vary the frequency of oscillation of the oscillator circuit.



FOR THE PURPOSES OF INFORMATION ONLY

Codes used to identify States party to the PCT on the front pages of pamphlets publishing international applications under the PCT.

AL	Albania	ES	Spain	LS	Lesotho	SI	Slovenia
AM	Armenia	FI	Finland	LT	Lithuania	SK	Slovakia
AT	Austria	FR	France	LU	Luxembourg	SN	Senegal
AU	Australia	GA	Gabon	LV	Latvia	SZ	Swaziland
AZ	Azerbaijan	GB	United Kingdom	MC	Monaco	TD	Chad
BA	Bosnia and Herzegovina	GE	Georgia	MD	Republic of Moldova	TG	Togo
BB	Barbados	GH	Ghana	MG	Madagascar	TJ	Tajikistan
BE	Belgium	GN	Guinea	MK	The former Yugoslav Republic of Macedonia	TM	Turkmenistan
BF	Burkina Faso	GR	Greece	ML	Mali	TR	Turkey
BG	Bulgaria	HU	Hungary	MN	Mongolia	TT	Trinidad and Tobago
BJ	Benin	IE	Ireland	MR	Mauritania	UA	Ukraine
BR	Brazil	IL	Israel	MW	Malawi	UG	Uganda
BY	Belarus	IS	Iceland	MX	Mexico	US	United States of America
CA	Canada	IT	Italy	NE	Niger	UZ	Uzbekistan
CF	Central African Republic	JP	Japan	NL	Netherlands	VN	Viet Nam
CG	Congo	KE	Kenya	NO	Norway	YU	Yugoslavia
CH	Switzerland	KG	Kyrgyzstan	NZ	New Zealand	ZW	Zimbabwe
CI	Côte d'Ivoire	KP	Democratic People's Republic of Korea	PL	Poland		
CM	Cameroon			PT	Portugal		
CN	China	KR	Republic of Korea	RO	Romania		
CU	Cuba	KZ	Kazakhstan	RU	Russian Federation		
CZ	Czech Republic	LC	Saint Lucia	SD	Sudan		
DE	Germany	LI	Liechtenstein	SE	Sweden		
DK	Denmark	LK	Sri Lanka	SG	Singapore		
EE	Estonia	LR	Liberia				

OSCILLATOR CIRCUIT

The present invention relates to an oscillator circuit, and more particularly to a tunable microwave oscillator and to motion detectors which utilise such oscillators.

Typically, an electronically tunable microwave oscillator can utilise a reverse biased varactor having a capacitance which varies according to a corresponding variation in an applied reverse modulation voltage. In order to effect a change in varactor capacitance, and hence to utilise the varactor as a practical frequency tuning device, a modulating signal of high magnitude is required. Typically, at a frequency of oscillation of about 10GHz, a variation of 30V in the applied reverse modulating voltage brings about a corresponding variation of about 20MHz in the frequency of oscillation of a tunable microwave oscillator utilising such a varactor. The frequency range over which the frequency of oscillation of a tunable microwave varactor oscillator can be varied is governed, in part, by the degree of capacitance change of the varactor over the range over which the modulating voltage is varied. A varactor oscillator is illustrated and described in "Dielectric Resonators" published by Artech House and in

GB2307355A. The relationship between the degree of frequency modulation and applied modulating signal is only linear for varactors over a narrow percentage bandwidth of up to 3%. Further, relatively large reverse biasing voltages are required for varactor oscillators in order to realise sufficient Q to establish and sustain oscillation. A typical biasing voltage is of the order of 20v to 30v. At these voltages the tuning range available is very limited.

10 The above renders the use of varactors undesirable for low noise oscillators.

It is an object of the present invention to at least mitigate some of the problems associated with 15 prior art tunable microwave oscillators, preferably, for use in motion detectors.

Accordingly, the present invention provides an oscillator circuit comprising first and second mutually 20 electro-magnetically couplable resonant circuits, the second resonant circuit comprising a dielectric element and excitation means operable to produce a first frequency of oscillation, the first resonant circuit comprising the dielectric element and excitation means, 25 including a forward biased two terminal device, operable responsive to an applied signal, to vary the resonant

frequency of the first resonant circuit and thereby vary the frequency of oscillation of the oscillator circuit.

Advantageously, an embodiment of the present 5 invention is provided wherein the forward biased two terminal device comprises a Schottky junction. Suitably, an embodiment is provided wherein the two terminal device is a Schottky device, for example, a Schottky diode.

10

Operating the Schottky diode in forward bias mode produces a relatively large variation in frequency in response to a relative small variation in modulating voltage. Furthermore, the voltages required to operate 15 a Schottky based oscillator are significantly less than those required to operate a varactor based oscillator.

Preferably, an embodiment of the present invention provides an oscillator circuit wherein the modes of 20 resonance have associated coupling points on the excitation means and the excitation means is arranged such that the coupling points are a substantially constant distance from the dielectric element.

25 A further embodiment of the invention provides an oscillator circuit wherein the dielectric element

comprises an arcuate profile and said excitation means is arranged to follow substantially the arcuate profile of the dielectric element.

5 Preferably, the excitation means comprises excitation strip lines or microstrip lines.

Embodiments of the present invention will now be described, by way of example only, with reference to the 10 accompanying drawings in which:

figure 1 illustrates schematically a typical transmit-receive arrangement of a motion detector;

15 figure 2 shows schematically a prior art oscillator for a motion detection device;

figure 3 depicts schematically an oscillator for a motion detection device according to an embodiment;

20 figure 4 illustrates the antenna patches of a microwave detector;

figure 5 shows a ground plane having two antenna 25 coupling slots for the microwave detector as is also illustrated in PCT/GB91/02099;

figure 6 depicts the microwave detector microstrip circuitry disposed on the opposite side of the board bearing the ground plane; and

5

figure 7 illustrates the microwave detectors microstrip circuitry having the components disposed thereon.

10 The use of the doppler effect for detecting motion is well known within the art. For example, in microwave intruder detection devices it is known to provide a dielectric resonator oscillator and diode mixer, mounted in a cavity, which are arranged to provide an output or 15 transmit signal at a required frequency and an input or receive signal, together with a doppler IF output.

Referring to figure 1, there is shown schematically a microwave circuit 100 having oscillator 102 producing 20 an output frequency f_o connected to a filter 104 arranged to pass the fundamental frequency of the oscillator, f_o , and to block the second and higher order harmonics thereof. The output from the filter 104 is fed to a power divider 106 to produce a transmit signal and a 25 local oscillator signal. A transmit antenna 108 is used to radiate the transmit signal. The local oscillator

signal 110 is fed to a mixer 112. The mixer 112 has an input from the receive antenna 114 arranged to receive the reflected signal. As is well appreciated within the art if the received signal was reflected from a moving object, it will be a doppler shifted version of the transmit signal. The mixer 112 combines the local oscillator signal with the received signal received by a receive antenna 114. The output 116 from the mixer 112 contains the doppler frequency produced by the reflection of the transmit signal of frequency f_0 from a moving body (not shown). The presence or absence of the doppler signal at the output 116 determines whether or not a moving object has been detected.

15 Referring to figure 2, there is shown schematically a prior art embodiment for a motion detector circuit having an oscillator 102 comprising first 201 and second 202 mutually coupled resonant circuits. The first resonant circuit 201 of the oscillator 102 arrangement 20 shown in figure 2 is a varactor 204 in conjunction with a microstrip line 206 arranged to resonate close to the frequency of operation of a dielectric resonator 208.

The second resonator circuit 202 comprises the 25 dielectric resonator 208 electromagnetically coupled, in use, to a further microstrip line 210 connected to the

gate of field effect transistor 214 and a microstrip line 211 connected to the drain of field effect transistor 214 and which forms part of the feedback loop of the oscillator. The FET 214 utilises various impedances which are arranged to correctly match the FET 214.

By varying or modulating the varactor capacitance with an applied voltage 222, the resonant frequency of 10 resonant circuit 201, can be tuned resulting in a change of oscillation frequency of the resonant circuit 202.

It will be appreciated by one skilled in the art that the closer the electromagnetic coupling between the 15 dielectric resonator and the microstrip lines, the greater the resultant frequency control. This increased frequency control is at the expense of decreased oscillator Q factor.

20 With reference to figure 3, there is shown an oscillator circuit for a microwave detector according to an embodiment of the present invention. The oscillator 300 comprises first 301 and second 302 mutually coupled resonant circuits.

The first resonant tuning circuit 301 consists of a

microstrip line 316 which has a Schottky diode 303 connected at one end, and a modulation voltage 322, $v(t)$, applied via resistor 307, to the other end of said microstrip line. The tuning line 316 is situated 5 adjacent to the dielectric resonator 308 so that, in use, the dielectric resonator 308 and the tuning line 316 are electromagnetically coupled.

Electronic frequency tuning of the oscillator 300 10 is achieved by varying the modulation voltage 322, which causes the junction capacitance of the Schottky diode 303 to vary. The change in capacitance brings about a change in the effective length of the tuning line 316 thereby altering the resonant frequency of the tuning 15 line 316. Since the first resonant tuning circuit 301 is mutually coupled to the second resonant circuit 302 via the dielectric resonator 308, the oscillation frequency of the oscillator 300 also varies according to the variation of the modulation voltage 322.

20

Preferably, the Schottky diode is a BAT15-03W available from Siemens operable at a diode voltage of close to OV. Under such operating conditions the variation in capacitance is as shown in table 1 below.

<u>V_F/V</u>	<u>C/ff</u>
-0.05	241

0.00	245
+0.05	252

TABLE 1

It will be appreciated that an increase in forward voltage from 0V to 0.05V brings about a 2.9% increase in capacitance.

In the present oscillator embodiment a DC voltage is applied to the Schottky diode 303 (connected in forward bias) via resistor 307. Typically, the frequency of the oscillator 300 is shifted by -12MHz from a nominal frequency of 10.525GHz, at an applied tuning voltage 322 of +5V. The frequency shift may be changed by altering the coupling to the dielectric resonator 308.

For comparison, a typical prior art varactor-tuned oscillator operating at a frequency of 10GHz requires a variation of up to 30V in the modulating voltage in order to produce a frequency shift of 20MHz.

The Schottky diode 303 is operated in a forward bias mode. This is in contrast to the varactor 204 of figure 2 which is operated in reverse bias. The higher

degree of change in junction capacitance of the Schottky diode 303 at small forward voltages is capitalised on, resulting in a relatively large change in effective length of tuning line 316, and hence large frequency 5 shift of the oscillator 300. The complete tunable oscillator 300 may thus be operated with voltages which are of significantly smaller magnitude as compared to the voltages used in conventional varactor-tuned oscillator 102. A significant reduction in component 10 and circuit cost thus results.

Although figure 3 shows the use of a single Schottky Diode, the present invention is not limited thereto. It will be appreciated by one skilled in the 15 art that diodes or diode pairs could equally well be utilised to realise an embodiment of the present invention. Furthermore, embodiments can also be realised in which the microstrip lines are arcuate as opposed to being straight. Still, further it will be 20 appreciated that the position of the circuit elements depicted in figure 3 et seq are not fixed and can be suitably repositioned without departing from the scope of the present invention. It will also be appreciated by one skilled in the art that there are many other 25 possible oscillator topologies which can be realised using the present invention.

Figure 4 shows the antenna circuit board 400 which can be of single-sided construction and carries separate transmit and receive antenna arrays. The transmit antenna array comprises two microstrip patch elements, 406 and 408, which are interconnected and connected to a common feed line 418. The receive antenna array also comprises two microstrip patch elements, 402 and 404, which are interconnected and connected to a common feed line 416. Various 2.2 mm holes B are provided to aid the positioning of the antenna board 400 to or on a suitable housing (not shown). Four 3 mm holes A1 and A2 are provided to secure the antenna board 400 to or within the housing (not shown). All dimensions are shown in 15 millimetres.

Figure 5 and 6 show the groundplane 500 and the component side circuitry 600 respectively of the microwave board. Figure 7 shows the component side of the microwave board 600 with the components mounted thereon. The oscillator circuit 700 is enclosed by the broken line. The oscillator circuit comprises a first 301 and second 302 electromagnetically couplable resonant circuits. The first resonant circuit comprises means for receiving a modulating voltage $v(t)$ including a connection tab 702, a 1KOhm resistor 307, a forward

biased Schottky diode 303 and a tuning line 316 electromagnetically couplable to the dielectric resonator 308.

5 The second circuit 302 comprises the dielectric resonator 308 coupled, via microstrip lines 310 and 311 to the gate and drain of a FHX35LPT transistor 314. Power is provided to the transistor 314 via a 39 Ohm resistor 704.

10

The output from the oscillator circuit 700 is fed via a decoupling capacitor 706 to the transmit 708 and receive 710 portions of the detector. The transmit portion 708 comprises a microstrip line 612 for coupling 15 to the transmit antenna. Similarly, the receive portion 710 receives via microstrip line 610 a reflected version of the transmitted signal. The microwave board 600 and the antenna circuit board 400 are mounted back-to-back with the groundplane intervening. The alignment of the 20 boards is such that the transmit array feed line 418 overlies the associated feed line 612 on the microwave board. Similarly, the receive array feed line 416 on the antenna board overlies the associated feed line 610 on the microwave board. Coupling between the microwave 25 circuit board and the antenna board is achieved by the provision of two narrow slots 502 and 504 in the

groundplane layer of the microwave board. The reflected signal and the output from the oscillator circuit are combined using a mixer diode 712, for example, a BAT15-099, to produce an IF signal which is output via 5 connection tab 608.

The reader's attention is directed to all papers and documents which are filed concurrently with or previous to this specification in connection with this 10 application and which are open to public inspection with this specification, and the contents of all such papers and documents are incorporated herein by reference.

All of the features disclosed in this specification 15 (including any accompanying claims, abstract and drawings), and/or all of the steps of any method or process so disclosed, may be combined in any combination, except combinations where at least some of such features and/or steps are mutually exclusive.

Each feature disclosed in this specification (including any accompanying claims, abstract and drawings), may be replaced by alternative features serving the same, equivalent or similar purpose, unless 25 expressly stated otherwise. Thus, unless expressly stated otherwise, each feature disclosed is one example

only of a generic series of equivalent or similar features.

The invention is not restricted to the details of
5 the foregoing embodiments. The invention extends to any
novel one, or any novel combination, of the features
disclosed in this specification (including any
accompanying claims, abstract and drawings), or to any
novel one, or any novel combination, of the steps of any
10 method or process so disclosed.

CLAIMS

1. An oscillator circuit (300) comprising first (301) and second (302) mutually electromagnetically couplable 5 resonant circuits, the second circuit (302) comprising a dielectric element (308) and excitation means (310,314,311) operable to produce a first frequency of oscillation, the first circuit (301) comprising the dielectric element (308), excitation means (316,303,307) 10 including a two-terminal Schottky device (303) operable, responsive to an applied signal (322), to vary the resonant frequency of the first resonant circuit (301), and thereby vary the frequency of oscillation of the oscillator circuit (300).

15

2. A circuit as claimed in claim 1, wherein the two terminal device Schottky device (303) is operable in forward bias mode.

20 3. A circuit as claimed in claim 2, wherein said Schottky device is a Schottky diode (303).

4. A circuit as claimed in any preceding claim, wherein the modes of resonance have associated coupling 25 points on the excitation means (310,311), and the excitation means (310,311) is arranged such that the

coupling points are a substantially constant distance from the dielectric element 308.

5. A circuit as claimed in claim 4, wherein the
5 dielectric element 308 comprises an arcuate profile and
said excitation means is arranged to follow
substantially the arcuate profile of the dielectric
element 308.

10 6. A circuit as claimed in claim any preceding claim,
wherein said excitation means (310,311,316) comprises
excitation microstrip lines.

7. An oscillator circuit substantially as described
15 herein with reference to and/or as illustrated in
figures 3 to 7.

8. A motion detection device comprising an oscillator
circuit as claimed in any preceding claim.

9. A motion detection device substantially as
described herein with reference to and/or as illustrated
in figure 3 to 7.

25 10. A microwave transmit/receive assembly comprising an
oscillator as claimed in any of claims 1 to 7.

11. A microwave transmit/receive assembly substantially as described herein with reference to and/or as illustrated by any or all of figures 3 to 7.

1/6

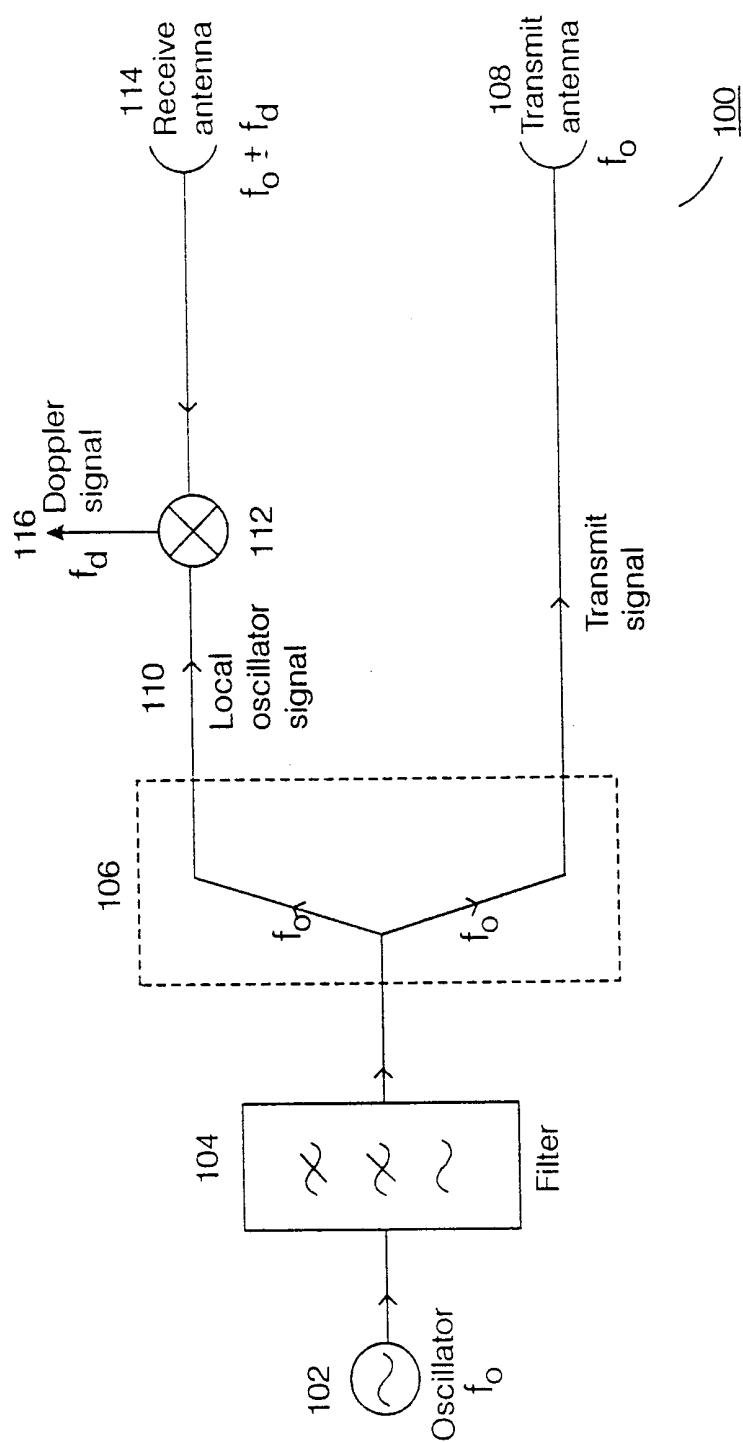


Fig. 1

2/6

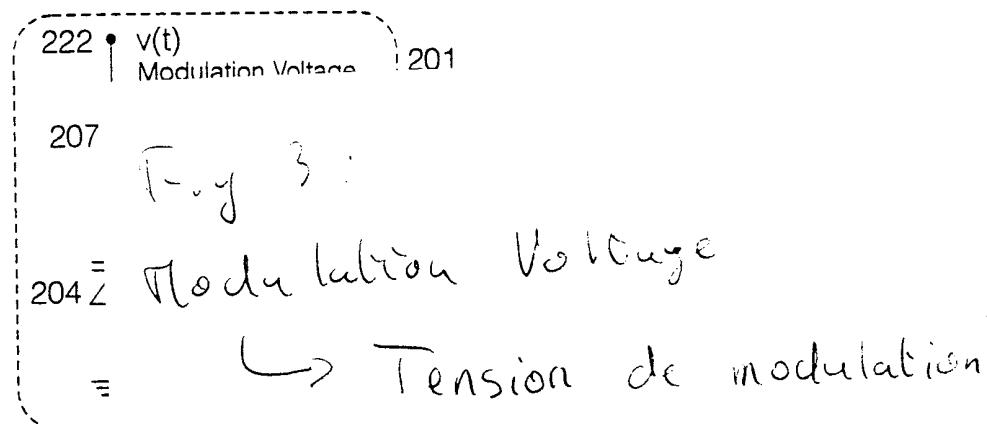
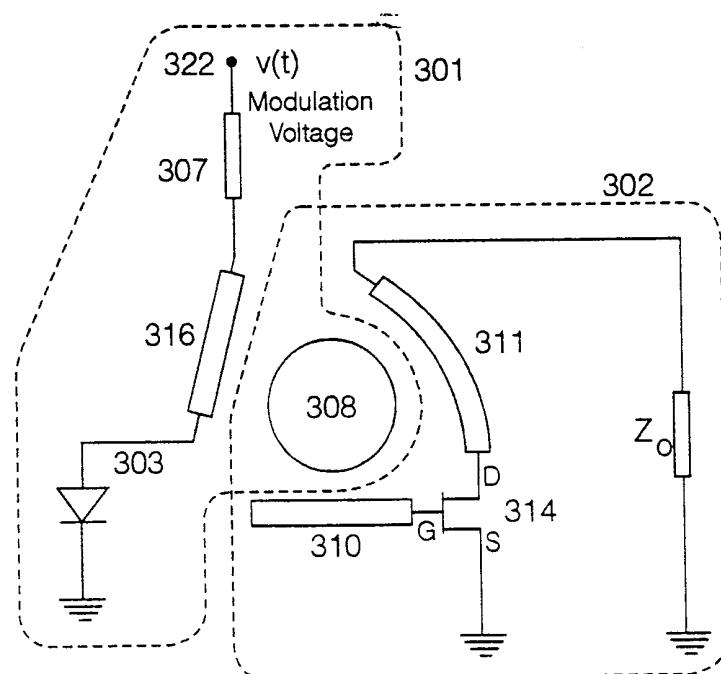


Fig.
Prior Art



3/6

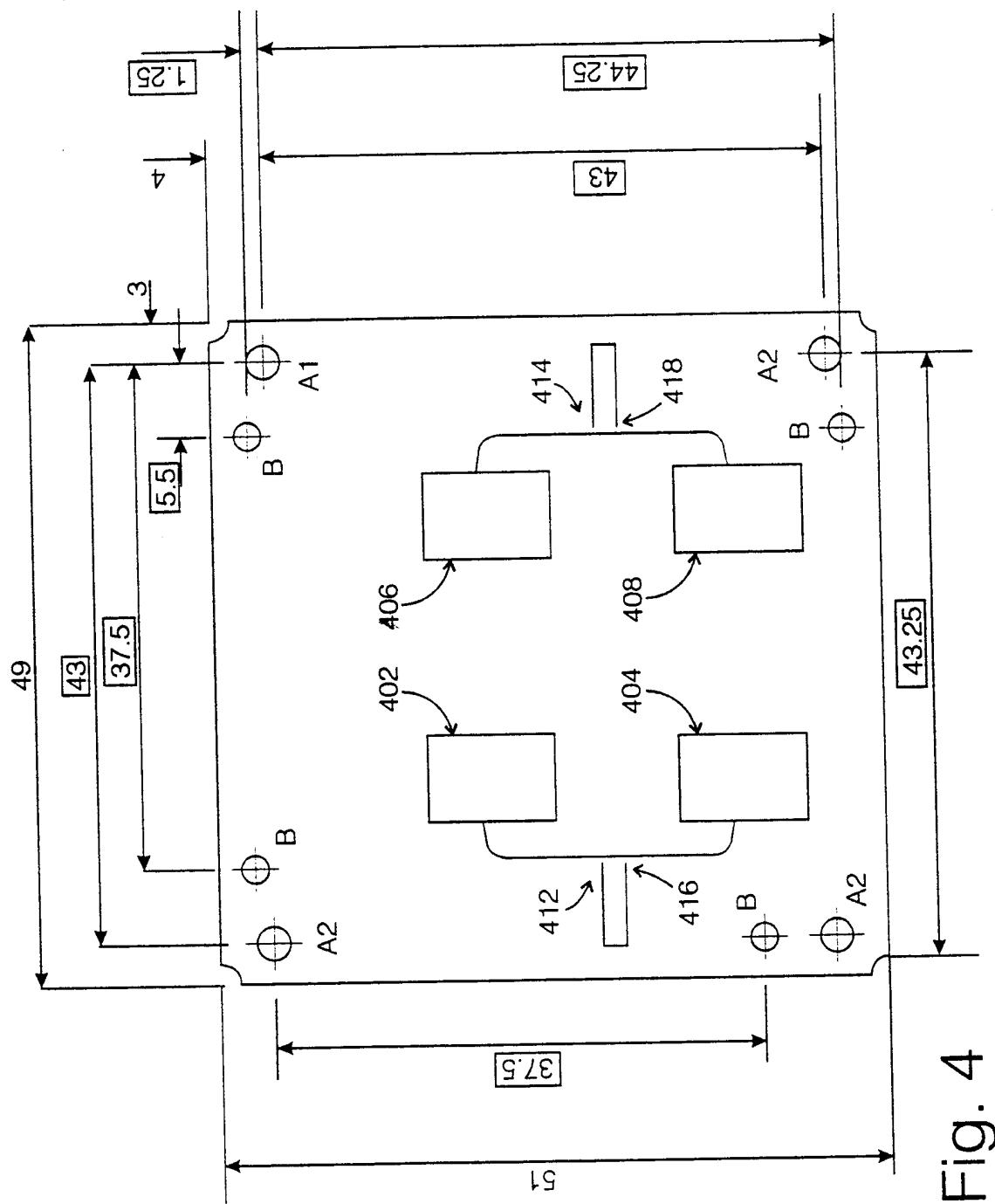


FIG. 4

4/6

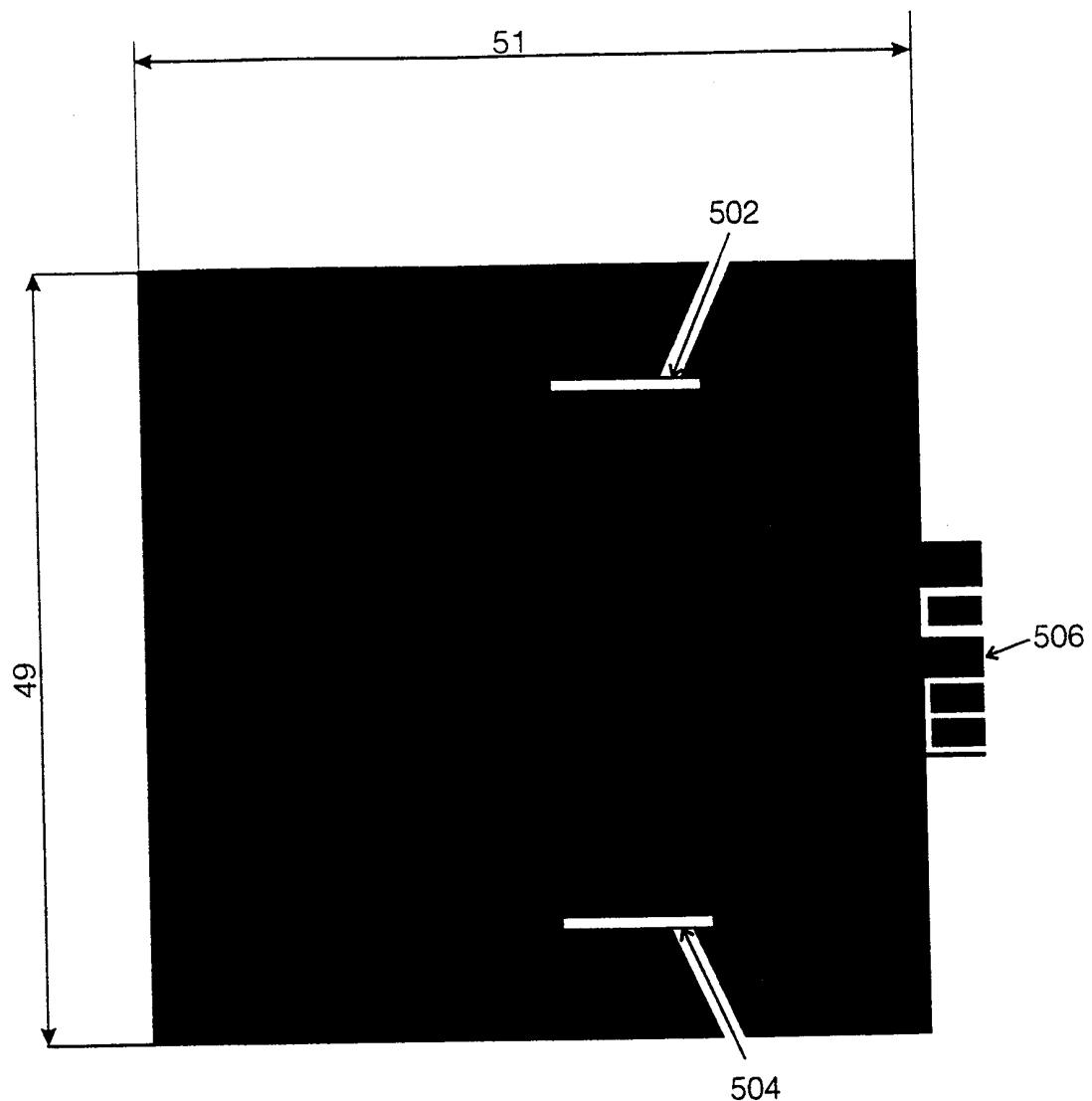


Fig. 5

5/6

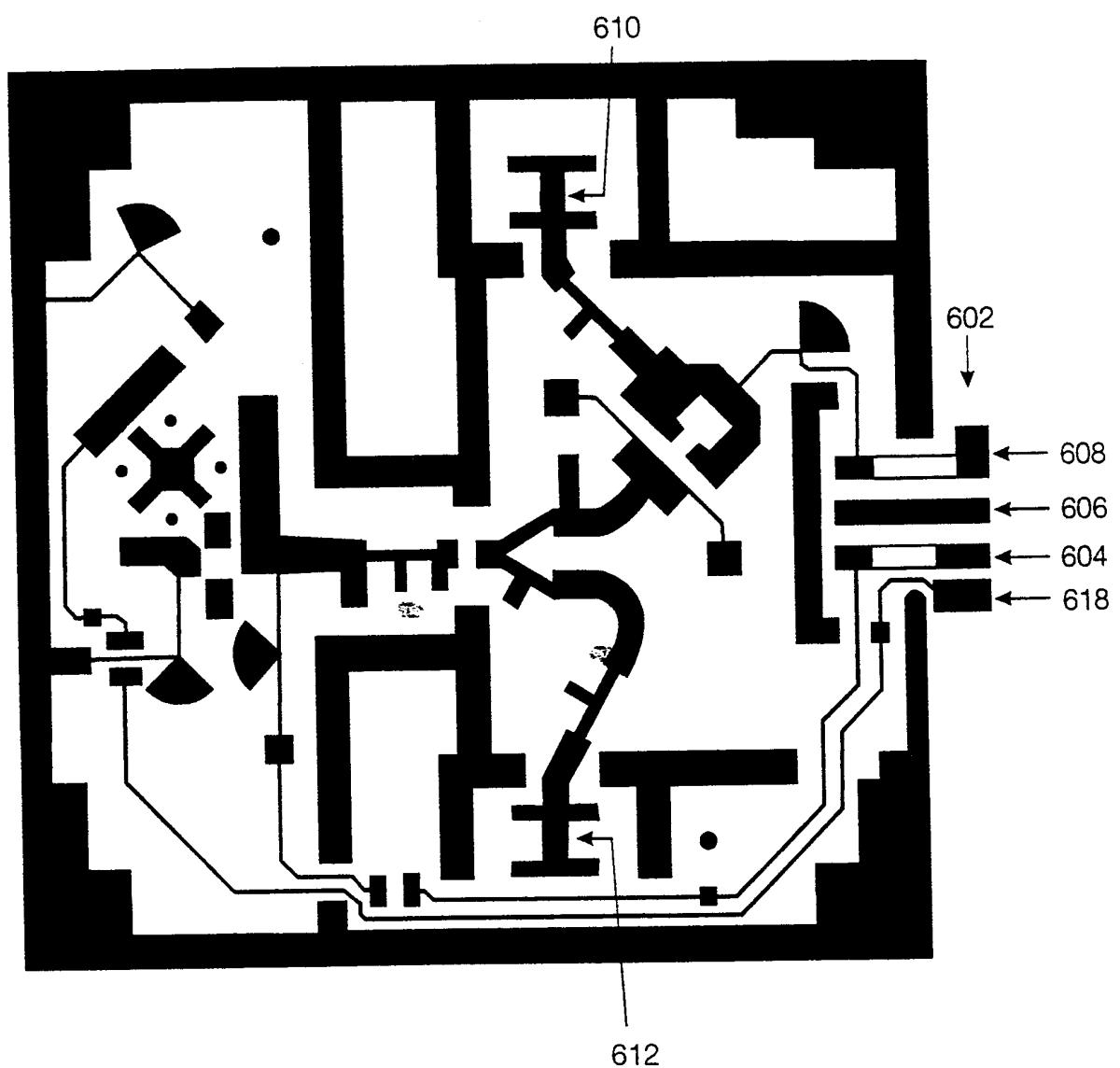


Fig. 6

6/6

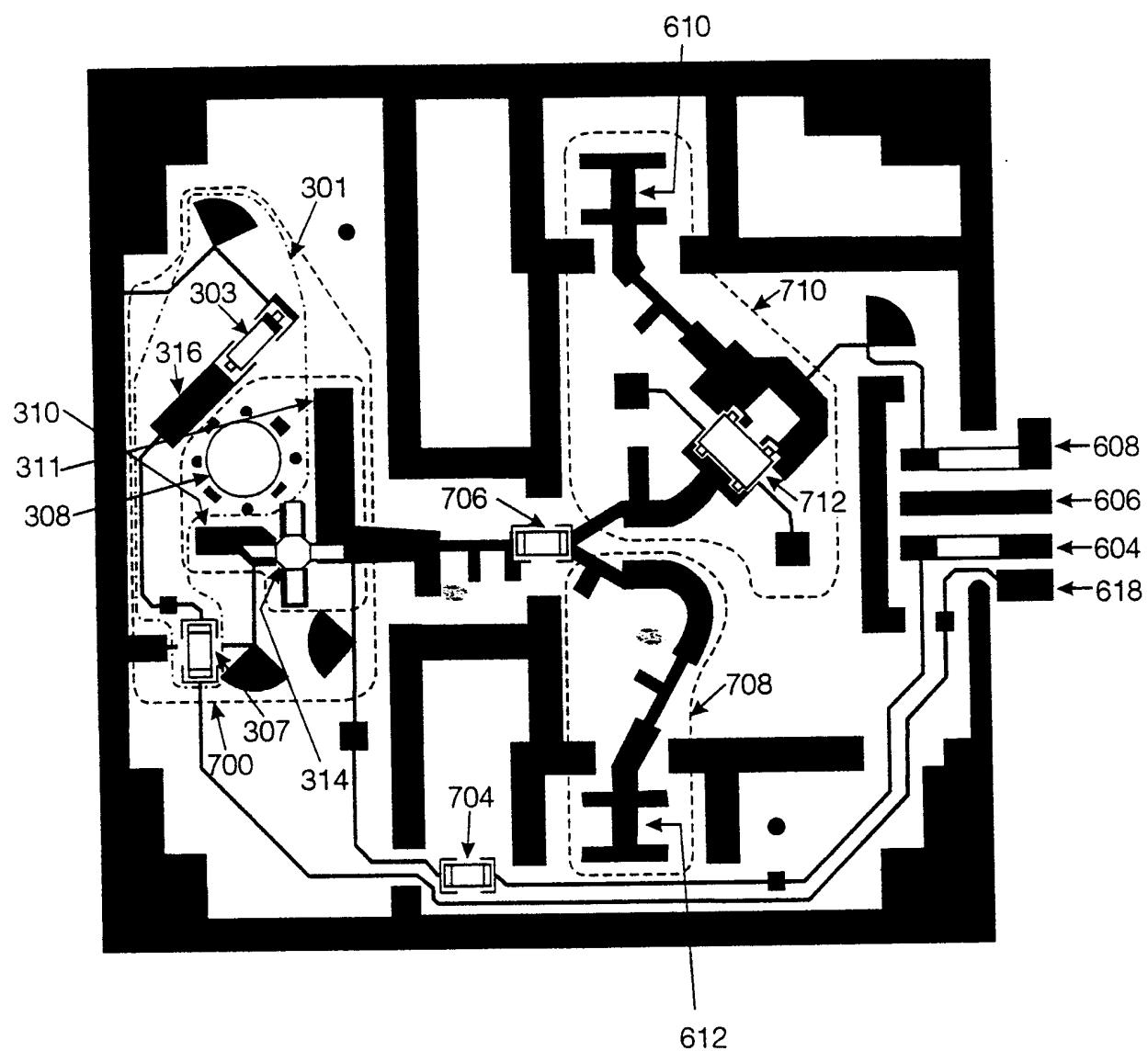


Fig. 7

INTERNATIONAL SEARCH REPORT

International Application No
PCT/GB 99/01667

A. CLASSIFICATION OF SUBJECT MATTER
IPC 6 H03B5/18 G01S7/03

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)
IPC 6 H03B G01S

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category °	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	<p>LEE J Y ET AL: "VOLTAGE CONTROLLED DIELECTRIC RESONATOR OSCILLATOR USING THREE- TERMINAL MESFET VARACTOR" ELECTRONICS LETTERS, vol. 30, no. 16, 4 August 1994 (1994-08-04), page 1320/1321 XP000468811 ISSN: 0013-5194 the whole document</p> <p style="text-align: center;">---</p> <p style="text-align: center;">-/-</p>	1-3,6,8, 10

Further documents are listed in the continuation of box C.

Patent family members are listed in annex.

° Special categories of cited documents :

- "A" document defining the general state of the art which is not considered to be of particular relevance
- "E" earlier document but published on or after the international filing date
- "L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)
- "O" document referring to an oral disclosure, use, exhibition or other means
- "P" document published prior to the international filing date but later than the priority date claimed

"T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention

"X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone

"Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art.

"&" document member of the same patent family

Date of the actual completion of the international search

Date of mailing of the international search report

16 September 1999

22/09/1999

Name and mailing address of the ISA

European Patent Office, P.B. 5818 Patentlaan 2
NL - 2280 HV Rijswijk
Tel. (+31-70) 340-2040, Tx. 31 651 epo nl,
Fax: (+31-70) 340-3016

Authorized officer

Dhondt, I

INTERNATIONAL SEARCH REPORT

International Application No
PCT/GB 99/01667

C.(Continuation) DOCUMENTS CONSIDERED TO BE RELEVANT

Category	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
A	<p>ELAAD D: "VOLTAGE CONTROLLED OSCILLATOR STABILIZED BY A DIELECTRIC RESONATOR" PROCEEDINGS OF THE CONFERENCE OF ELECTRICAL AND ELECTRONICS ENGINEERS IN ISRAEL, TEL AVIV, APR. 7 - 9, 1987, no. CONF. 15, 7 April 1987 (1987-04-07), pages 1-3, XP000124841 INSTITUTE OF ELECTRICAL AND ELECTRONICS ENGINEERS page 1, column 2, line 1 -page 2, column 1, line 15; figures 1-5</p> <p>---</p>	1
A	<p>BATTIBOIA S ET AL: "LOW-POWER X-BAND RADAR FOR INDOOR BURGLAR ALARMS" IEEE TRANSACTIONS ON MICROWAVE THEORY AND TECHNIQUES, vol. 43, no. 7, PART 02, 1 July 1995 (1995-07-01), pages 1710-1714, XP000514156 ISSN: 0018-9480</p> <p>---</p>	8,10
A	<p>INOUE T ET AL: "60GHZ DIELECTRICALLY STABILIZED MONOLITHIC VOLTAGE CONTROLLED OSCILLATOR" PROCEEDINGS OF THE 25TH. EUROPEAN MICROWAVE CONFERENCE 1995, BOLOGNA, SEPT. 4 - 7, 1995, vol. 1, no. CONF. 25, 4 September 1995 (1995-09-04), pages 281-284, XP000740166 EUROPEAN MICROWAVE CONFERENCE COMMITTEE ISBN: 1-899919-15-5 page 281, column 2, line 1 - line 32; figures 3,7</p> <p>---</p>	1
A	<p>US 4 754 236 A (MAMODALY NARGUISE ET AL) 28 June 1988 (1988-06-28) column 2, line 52 -column 4, line 7; figures 1-3</p> <p>---</p>	1
A	<p>EP 0 836 271 A (PHILIPS ELECTRONICS NV) 15 April 1998 (1998-04-15) column 3, line 44 - line 56; figure 1</p> <p>---</p>	1
A	<p>US 5 497 163 A (LOHNINGER GERHARD ET AL) 5 March 1996 (1996-03-05) abstract; figures 4-7</p> <p>----</p>	8,10

INTERNATIONAL SEARCH REPORT

International Application No

PCT/GB 99/01667

Patent document cited in search report	Publication date	Patent family member(s)		Publication date
US 4754236	A 28-06-1988	FR 2597678	A 23-10-1987	
		EP 0242292	A 21-10-1987	
		JP 62252206	A 04-11-1987	
EP 0836271	A 15-04-1998	JP 10145190	A 29-05-1998	
		US 5937340	A 10-08-1999	
US 5497163	A 05-03-1996	EP 0638818	A 15-02-1995	
		AT 180575	T 15-06-1999	
		DE 59309609	D 01-07-1999	
		JP 7055917	A 03-03-1995	